

Welcome to E-XFL.COM

What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	S08
Core Size	8-Bit
Speed	20MHz
Connectivity	LINbus, SCI
Peripherals	LVD, POR, PWM
Number of I/O	24
Program Memory Size	4KB (4K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	256 x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 8x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Through Hole
Package / Case	28-DIP (0.600", 15.24mm)
Supplier Device Package	28-PDIP
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mc9s08se4crl

2 Pin Assignments

This chapter shows the pin assignments in the packages available for the MC9S08SE8 series.

Table 1. Pin Availability by Package Pin-Count

Pin Number (Package)		<-- Lowest Priority --> Highest			
28 (SOIC/PDIP)	16 (TSSOP)	Port Pin	Alt 1	Alt 2	Alt 3
1	—	PTC5			
2	—	PTC4			
3	1	PTA5	IRQ	TCLK	RESET
4	2	PTA4		BKGD	MS
5	3				V _{DD}
6	—			V _{DDA}	V _{REFH}
7	—			V _{SSA}	V _{REFL}
8	4				V _{SS}
9	5	PTB7	EXTAL		
10	6	PTB6	XTAL		
11	7	PTB5			
12	8	PTB4		TPM2CH0	
13	—	PTC3			
14	—	PTC2			
15	—	PTC1			
16	—	PTC0			
17	9	PTB3	KBIP7		ADP9
18	10	PTB2	KBIP6		ADP8
19	11	PTB1	KBIP5	TxD	ADP7
20	12	PTB0	KBIP4	RxD	ADP6
21	—	PTA7		TPM1CH1 ¹	ADP5
22	—	PTA6		TPM1CH0 ¹	ADP4
23	13	PTA3	KBIP3		ADP3
24	14	PTA2	KBIP2		ADP2
25	15	PTA1	KBIP1	TPM1CH1 ¹	ADP1
26	16	PTA0	KBIP0	TPM1CH0 ¹	ADP0
27	—	PTC7			
28	—	PTC6			

¹ TPM1 pins can be remapped to PTA7, PTA6 and PTA1,PTA0

3 Electrical Characteristics

This chapter contains electrical and timing specifications.

3.1 Parameter Classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding, the following classification is used and the parameters are tagged accordingly in the tables where appropriate:

Table 2. Parameter Classifications

P	Those parameters are guaranteed during production testing on each individual device.
C	Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.
T	Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category.
D	Those parameters are derived mainly from simulations.

NOTE

The classification is shown in the column labeled “C” in the parameter tables where appropriate.

3.2 Absolute Maximum Ratings

Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the limits specified in [Table 3](#) may affect device reliability or cause permanent damage to the device. For functional operating conditions, refer to the remaining tables in this section.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, either V_{SS} or V_{DD}) or the programmable pull-up resistor associated with the pin is enabled.

Table 3. Absolute Maximum Ratings

Rating	Symbol	Value	Unit
Supply voltage	V_{DD}	-0.3 to 5.8	V
Maximum current into V_{DD}	I_{DD}	120	mA
Digital input voltage	V_{In}	-0.3 to $V_{DD} + 0.3$	V
Instantaneous maximum current Single pin limit (applies to all port pins) ^{1, 2, 3}	I_D	±25	mA
Storage temperature range	T_{stg}	-55 to 150	°C

- ¹ Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive (V_{DD}) and negative (V_{SS}) clamp voltages, then use the larger of the two resistance values.
- ² All functional non-supply pins are internally clamped to V_{SS} and V_{DD} .
- ³ Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If positive injection current ($V_{In} > V_{DD}$) is greater than I_{DD} , the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure external V_{DD} load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if the clock rate is very low (which would reduce overall power consumption).

3.3 Thermal Characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits, and it is user-determined rather than being controlled by the MCU design. To take $P_{I/O}$ into account in power calculations, determine the difference between actual pin voltage and V_{SS} or V_{DD} and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and V_{SS} or V_{DD} will be very small.

Table 4. Thermal Characteristics

Rating	Symbol	Value	Unit	
Operating temperature range (packaged)	T_A	T_L to T_H	°C	
C		-40 to 85		
V		-40 to 105		
M		-40 to 125		
Maximum junction temperature	T_{JM}	135	°C	
Thermal resistance single-layer board	θ_{JA}	28-pin SOIC	70	°C/W
		28-pin PDIP	68	
		16-pin TSSOP	129	
Thermal resistance four-layer board		28-pin SOIC	48	°C/W
		28-pin PDIP	49	
		16-pin TSSOP	85	

Electrical Characteristics

The average chip-junction temperature (T_J) in °C can be obtained from:

$$T_J = T_A + (P_D \times \theta_{JA}) \quad \text{Eqn. 1}$$

Where:

T_A = Ambient temperature, °C

θ_{JA} = Package thermal resistance, junction-to-ambient, °C/W

$P_D = P_{int} + P_{I/O}$

$P_{int} = I_{DD} \times V_{DD}$, Watts — chip internal power

$P_{I/O}$ = Power dissipation on input and output pins — user-determined

For most applications, $P_{I/O} \ll P_{int}$ and can be neglected. An approximate relationship between P_D and T_J (if $P_{I/O}$ is neglected) is:

$$P_D = K \div (T_J + 273^\circ\text{C}) \quad \text{Eqn. 2}$$

Solving [Equation 1](#) and [Equation 2](#) for K gives:

$$K = P_D \times (T_A + 273^\circ\text{C}) + \theta_{JA} \times (P_D)^2 \quad \text{Eqn. 3}$$

Where K is a constant pertaining to the particular part. K can be determined from [Equation 3](#) by measuring P_D (at equilibrium) for a known T_A . Using this value of K, the values of P_D and T_J can be obtained by solving [Equation 1](#) and [Equation 2](#) iteratively for any value of T_A .

3.4 ESD Protection and Latch-Up Immunity

Although damage from electrostatic discharge (ESD) is much less common on these devices than on early CMOS circuits, normal handling precautions should be used to avoid exposure to static discharge. Qualification tests are performed to ensure that these devices can withstand exposure to reasonable levels of static without suffering any permanent damage.

During the device qualification ESD stresses were performed for the human body model (HBM), the machine model (MM) and the charge device model (CDM).

A device is defined as a failure if after exposure to ESD pulses the device no longer meets the device specification. Complete DC parametric and functional testing is performed per the applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

Table 5. ESD and Latch-up Test Conditions

Model	Description	Symbol	Value	Unit
Human body	Series resistance	R1	1500	Ω
	Storage capacitance	C	100	pF
	Number of pulses per pin	—	3	—
Machine	Series resistance	R1	0	Ω
	Storage capacitance	C	200	pF
	Number of pulses per pin	—	3	—

Table 7. DC Characteristics (continued)

Num	C	Parameter	Symbol	Min	Typical ¹	Max	Unit
25	T	Low-voltage inhibit reset/recover hysteresis	V_{hys}	5 V	—	100	mV
				3 V	—	60	
26	P	Bandgap voltage reference ⁹	V_{BG}	1.18	1.20	1.21	V

¹ Typical values are measured at 25 °C. Characterized, not tested.

² Measured with $V_{In} = V_{DD}$ or V_{SS} .

³ Measured with $V_{In} = V_{SS}$.

⁴ Measured with $V_{In} = V_{DD}$.

⁵ All functional non-supply pins are internally clamped to V_{SS} and V_{DD} .

⁶ Input must be current-limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the larger of the two values.

⁷ Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If positive injection current ($V_{In} > V_{DD}$) is greater than I_{DD} , the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure external V_{DD} load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if clock rate is very low (which would reduce overall power consumption).

⁸ Maximum is highest voltage that POR is guaranteed.

⁹ Factory trimmed at $V_{DD} = 5.0$ V, Temp = 25 °C.

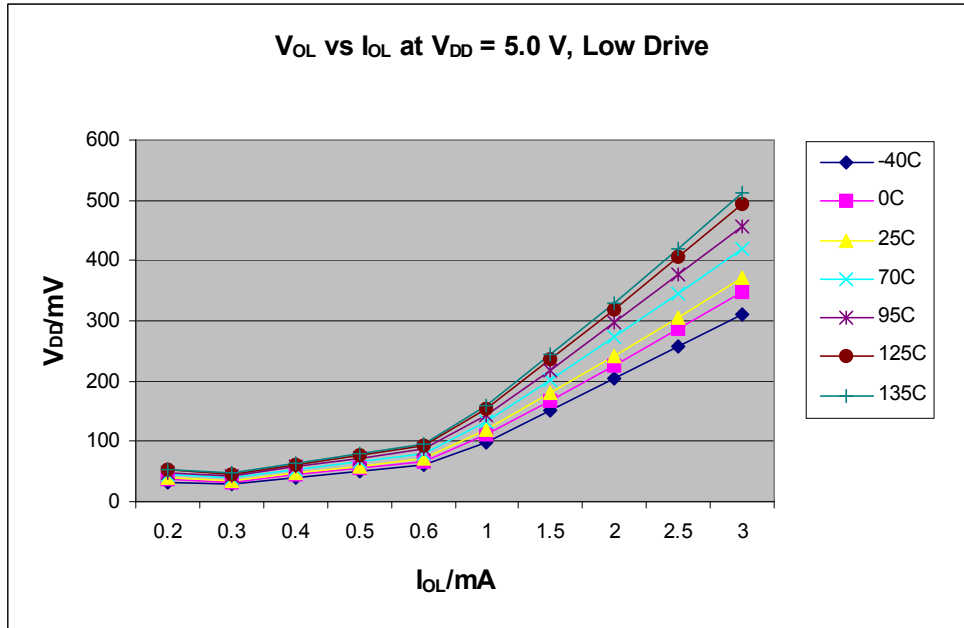


Figure 6. Typical V_{OL} vs. I_{OL} for Low Drive Enabled Pad ($V_{DD} = 5$ V)

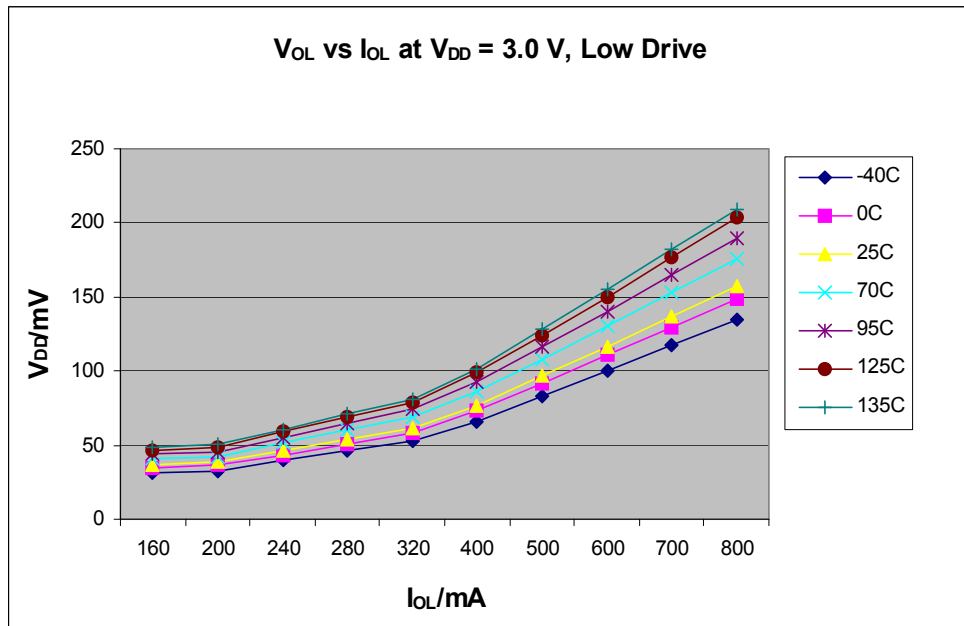


Figure 7. Typical V_{OL} vs. I_{OL} for Low Drive Enabled Pad ($V_{DD} = 3$ V)

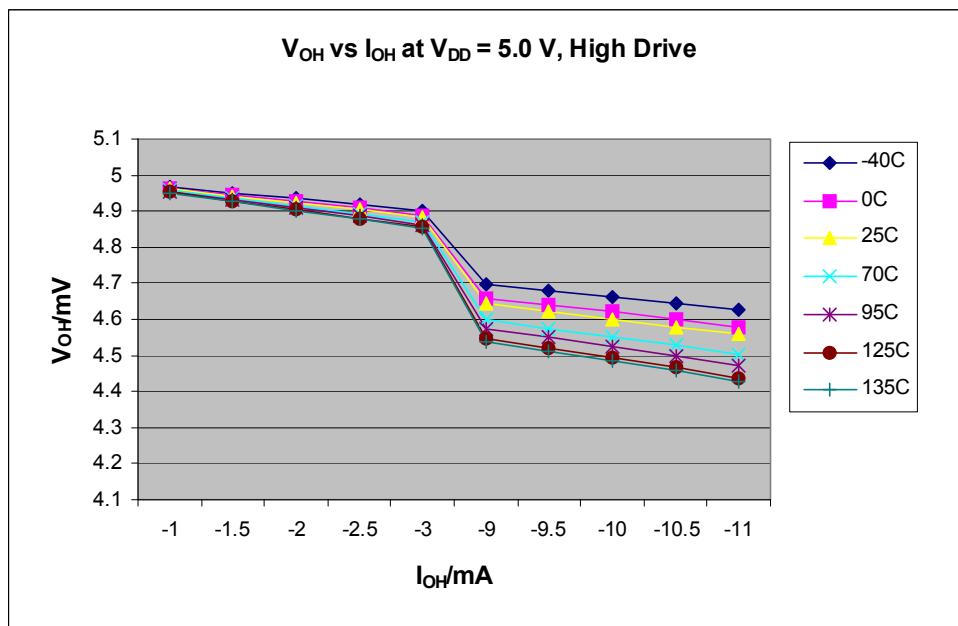


Figure 8. Typical V_{OH} vs. I_{OH} for High Drive Enabled Pad (V_{DD} = 5 V)

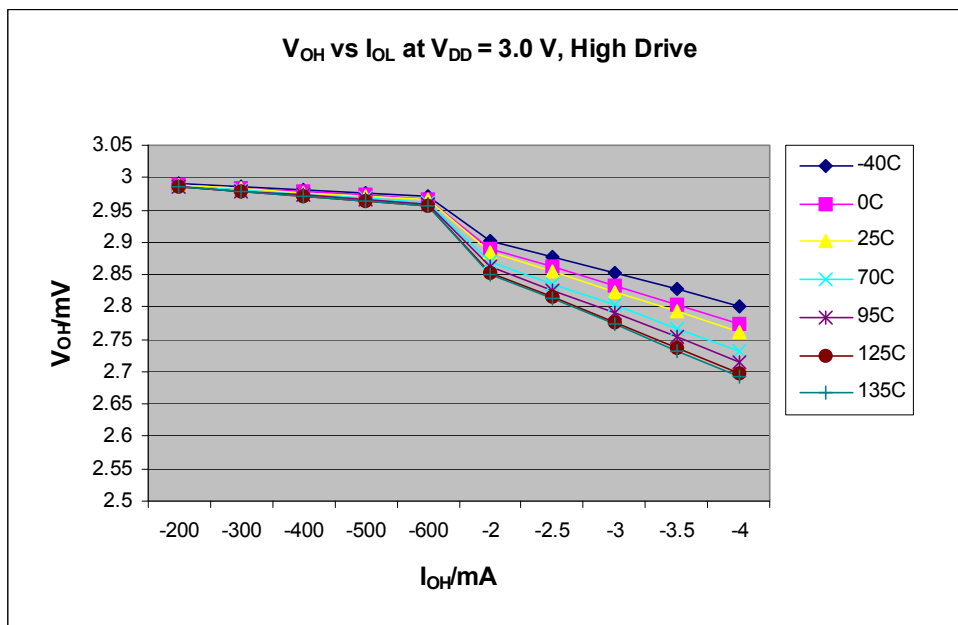


Figure 9. Typical V_{OH} vs. I_{OH} for High Drive Enabled Pad (V_{DD} = 3 V)

Table 8. Supply Current Characteristics

Num	C	Parameter	Symbol	V _{DD} (V)	Typical ¹	Max	Unit	Temp (°C)
1	C	Run supply current ² measured at (CPU clock = 4 MHz, f _{Bus} = 2 MHz)	R _I DD	5	2.4	2.72	mA	-40 to 125
				3	2.18	2.26		
2	P	Run supply current ² measured at (CPU clock = 20 MHz, f _{Bus} = 10 MHz)	R _I DD	5	6.35	7.29	mA	-40 to 125
				3	5.79	6.42		
3	P	Wait supply current ² measured at f _{Bus} = 2 MHz	W _I DD	5	1.4	1.56	mA	-40 to 125
				3	1.36	1.53		
4	P	Stop2 mode supply current	S2 _I DD	5	1.4	19 28 45.8	μA	-40 to 85 -40 to 105 -40 to 125
				3	1.3	15 22 37.2		
5	P	Stop3 mode supply current	S3 _I DD	5	1.61	23 43 76.1	μA	-40 to 85 -40 to 105 -40 to 125
				3	1.44	19 38 66.4		
6	P	RTC adder to stop2 or stop3 ³	S23 _I DDRTI	5	300	500 500	nA	-40 to 85 -40 to 125
				3	300	500 500		
7	C	LVD adder to stop3 (LVDE = LVDSE = 1)	S3 _I DDLVD	5	122	180	μA	-40 to 125
				3	110	160		
8	C	Adder to stop3 for oscillator enabled ⁴ (OSCSTEN = 1)	S3 _I DDOSC	5,3	5	8	μA	-40 to 125

¹ Typical values are based on characterization data at 25 °C unless otherwise stated. See Figure 12 through Figure 13 for typical curves across voltage/temperature.

² All modules except ADC active, ICS configured for FBE, and does not include any dc loads on port pins.

³ Most customers are expected to find that auto-wakeup from stop2 or stop3 can be used instead of the higher current wait mode. Wait mode typical is 220 μA at 5 V with f_{Bus} = 1 MHz.

⁴ Values given under the following conditions: low range operation (RANGE = 0) with a 32.768 kHz crystal and low power mode (HGO = 0).

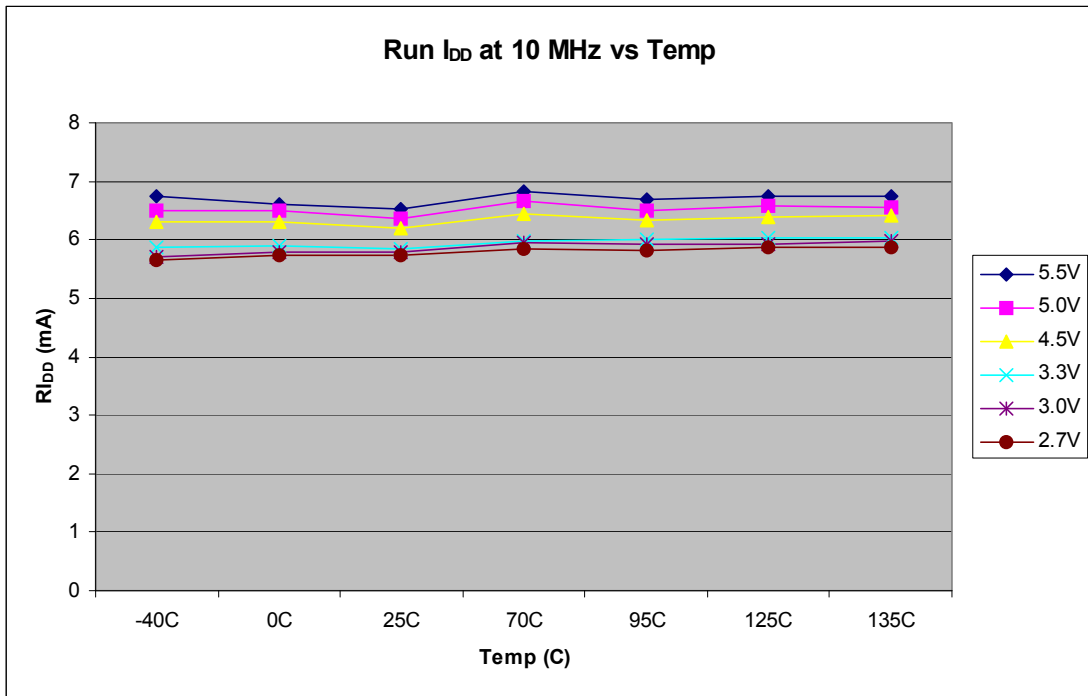


Figure 12. Typical Run I_{DD} Curves

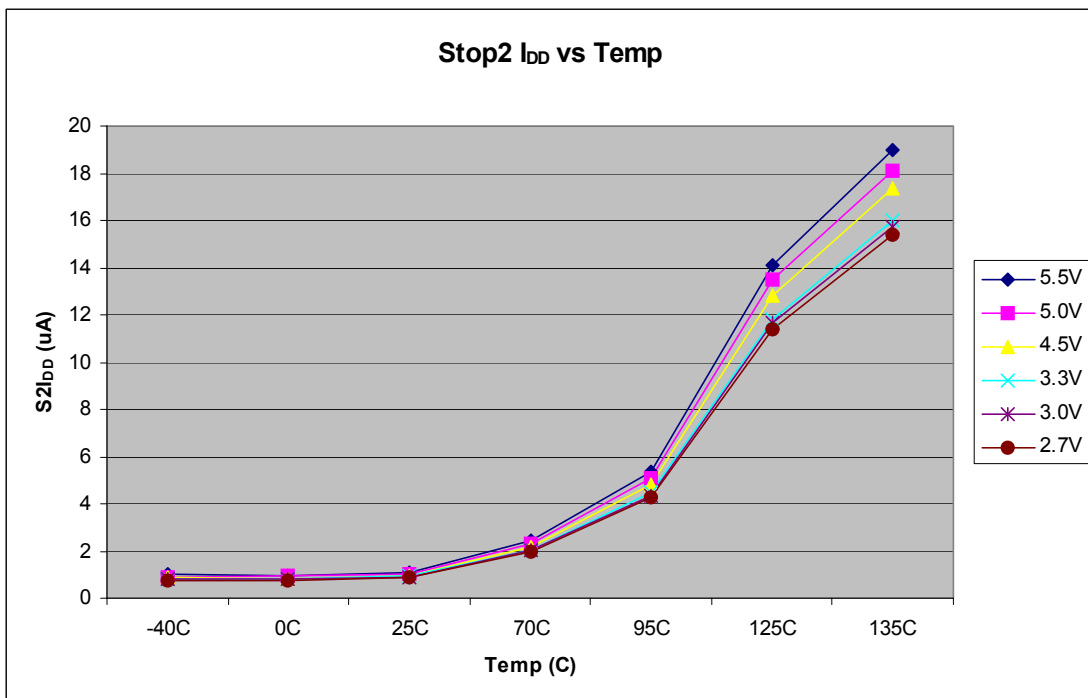


Figure 13. Typical Stop2 I_{DD} Curves

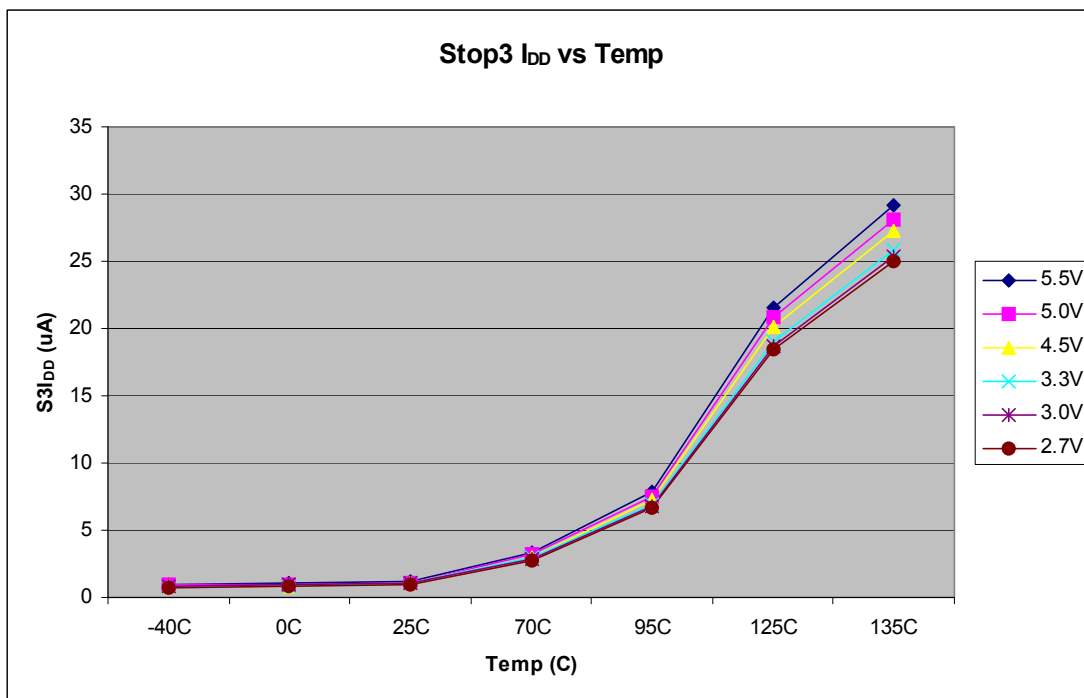


Figure 14. Typical Stop3 I_{DD} Curves

3.7 External Oscillator (XOSC) Characteristics

Table 9. Oscillator electrical specifications (Temperature Range = -40 to 125°C Ambient)

Num	C	Characteristic	Symbol	Min.	Typical ¹	Max.	Unit	
1	C	Oscillator crystal or resonator (EREFS = 1, ERCLKEN = 1)						
		Low range (RANGE = 0)	f_{lo}	32	—	38.4	kHz	
		High range (RANGE = 1), high gain (HGO = 1) ²	f_{hi-hgo}	1	—	16	MHz	
		High range (RANGE = 1), low power (HGO = 0) ²	f_{hi-lp}	1	—	8	MHz	
2	—	Load capacitors	C_1, C_2	See crystal or resonator manufacturer's recommendation				
3	—	Feedback resistor	R_F	—	10	—	MΩ	
		Low range (32 kHz to 100 kHz)						1
4	—	Series resistor	R_S	—	0	—	kΩ	
		Low range, low gain (RANGE = 0, HGO = 0)						100
		Low range, high gain (RANGE = 0, HGO = 1)						0
	High range, low gain (RANGE = 1, HGO = 0)	0						
	High range, high gain (RANGE = 1, HGO = 1)	0						
		≥ 8 MHz	—	0	0			
		4 MHz	—	0	10			
		1 MHz	—	0	20			

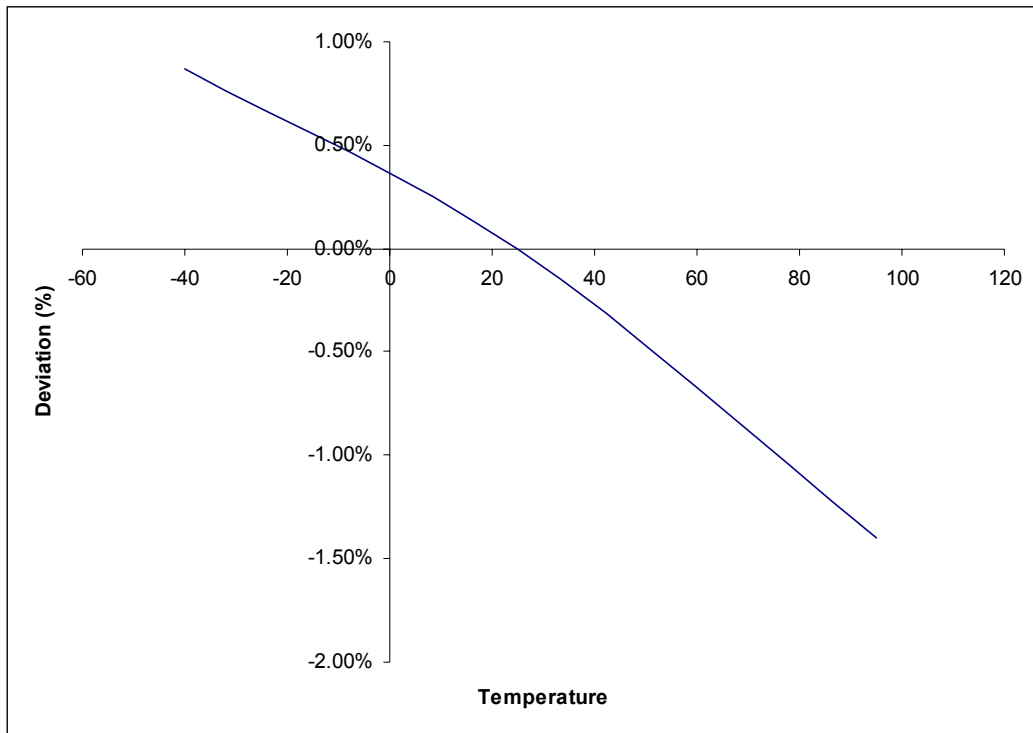


Figure 17. Deviation of DCO Output from Trimmed Frequency (20 MHz, 3.0 V)

3.9 ADC Characteristics

Table 11. 10-Bit ADC Operating Conditions

Characteristic	Conditions	Symb	Min	Typ ¹	Max	Unit	Comment
Supply voltage	Absolute	V_{DDA}	2.7	—	5.5	V	
	Delta to V_{DD} ($V_{DD} - V_{DDA}$) ²	ΔV_{DDA}	-100	0	100	mV	
Ground voltage	Delta to V_{SS} ($V_{SS} - V_{SSA}$) ²	ΔV_{SSA}	-100	0	100	mV	
Input voltage		V_{ADIN}	V_{REFL}	—	V_{REFH}	V	
Input capacitance		C_{ADIN}	—	4.5	5.5	pF	
Input resistance		R_{ADIN}	—	3	5	k Ω	
Analog source resistance	10-bit mode $f_{ADCK} > 4\text{MHz}$ $f_{ADCK} < 4\text{MHz}$	R_{AS}	—	—	5	k Ω	External to MCU
	8-bit mode (all valid f_{ADCK})		—	—	10		
ADC conversion clock frequency	High speed (ADLPC = 0)	f_{ADCK}	0.4	—	8.0	MHz	
	Low power (ADLPC = 1)		0.4	—	4.0		

Electrical Characteristics

- Typical values assume $V_{DDA} = 5.0\text{ V}$, $\text{Temp} = 25\text{ }^{\circ}\text{C}$, $f_{ADCK} = 1.0\text{ MHz}$ unless otherwise stated. Typical values are for reference only and are not tested in production.
- DC potential difference.

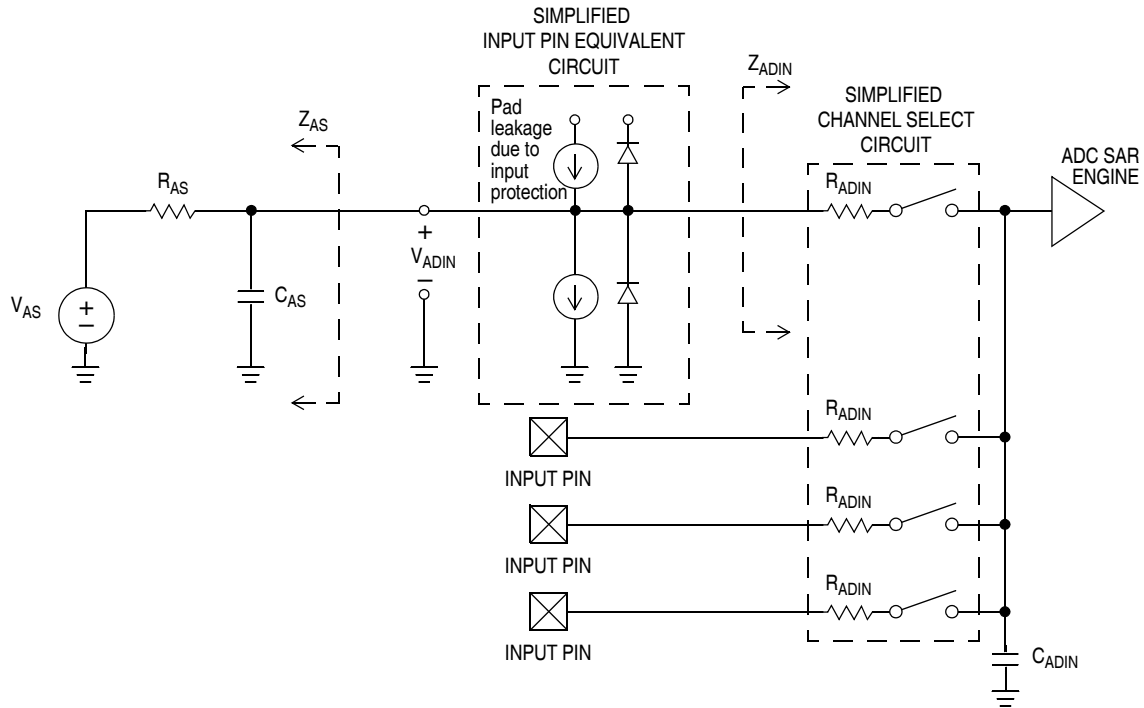


Figure 18. ADC Input Impedance Equivalency Diagram

Table 12. 10-Bit ADC Characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

Characteristic	Conditions	C	Symb	Min	Typ ¹	Max	Unit	Comment
Supply Current ADLPC = 1 ADLSMP = 1 ADCO = 1		T	I_{DDA}	—	133	—	μA	
Supply Current ADLPC = 1 ADLSMP = 0 ADCO = 1		T	I_{DDA}	—	218	—	μA	
Supply Current ADLPC = 0 ADLSMP = 1 ADCO = 1		T	I_{DDA}	—	327	—	μA	
Supply Current ADLPC = 0 ADLSMP = 0 ADCO = 1		D	I_{DDA}	—	0.582	1	mA	
Supply Current	Stop, Reset, Module Off	D	I_{DDA}	—	0.011	1	μA	

Electrical Characteristics

Table 12. 10-Bit ADC Characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) (continued)

Characteristic	Conditions	C	Symb	Min	Typ ¹	Max	Unit	Comment
Differential Non-Linearity	10-bit mode ³	P	DNL	—	±0.5	±1.0	LSB ³	
	8-bit mode ³	P		—	±0.3	±0.5		
Integral Non-Linearity	10-bit mode	T	INL	—	±0.5	±1.0	LSB ³	
	8-bit mode	T		—	±0.3	±0.5		
Zero-Scale Error	10-bit mode	P	E_{ZS}	—	±1.5	±2.1	LSB ³	$V_{ADIN} = V_{SSA}$
	8-bit mode	P		—	±0.5	±0.7		
Full-Scale Error	10-bit mode	T	E_{FS}	—	±1	±1.5	LSB ³	$V_{ADIN} = V_{DDA}$
	8-bit mode	T		—	±0.5	±0.5		
Quantization Error	10-bit mode	D	E_Q	—	—	±0.5	LSB ³	
	8-bit mode			—	—	±0.5		
Input Leakage Error	10-bit mode	D	E_{IL}	—	±0.2	±2.5	LSB ³	Padleakage ^{4*} R_{AS}
	8-bit mode			—	±0.1	±1		

¹ Typical values assume $V_{DDA} = 5.0$ V, Temp = 25 °C, $f_{ADCK} = 1.0$ MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

² Monotonicity and No-Missing-Codes guaranteed in 10-bit and 8-bit modes

³ $1 \text{ LSB} = (V_{REFH} - V_{REFL})/2^N$

⁴ Based on input pad leakage current. Refer to pad electricals.

3.11 Flash Specifications

This section provides details about program/erase times and program-erase endurance for the flash memory.

Program and erase operations do not require any special power sources other than the normal V_{DD} supply. For more detailed information about program/erase operations, see the Memory section in the reference manual.

Table 15. Flash Characteristics

Num	C	Characteristic	Symbol	Min	Typical	Max	Unit
1	D	Supply voltage for program/erase	$V_{\text{prog/erase}}$	2.7	—	5.5	V
2	D	Supply voltage for read operation	V_{Read}	2.7	—	5.5	V
3	D	Internal FCLK frequency ¹	f_{FCLK}	150	—	200	kHz
4	D	Internal FCLK period (1/FCLK)	t_{Fcyc}	5	—	6.67	μs
5	P	Byte program time (random location) ²	t_{prog}	9			t_{Fcyc}
6	P	Byte program time (burst mode) ²	t_{Burst}	4			t_{Fcyc}
7	P	Page erase time ²	t_{Page}	4000			t_{Fcyc}
8	P	Mass erase time ²	t_{Mass}	20,000			t_{Fcyc}
9	C	Program/erase endurance ³ T_L to T_H = -40 °C to 125 °C T = 25 °C	n_{FLPE}	10,000	— 100,000	—	cycles
10	C	Data retention ⁴	$t_{\text{D_ret}}$	15	100	—	years

¹ The frequency of this clock is controlled by a software setting.

² These values are hardware state machine controlled. User code does not need to count cycles. This information supplied for calculating approximate time to program and erase.

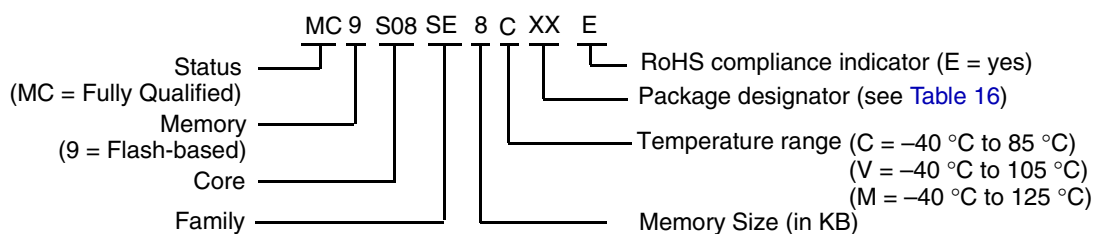
³ **Typical endurance for flash** was evaluated for this product family on the 9S12Dx64. For additional information on how Freescale defines typical endurance, please refer to Engineering Bulletin EB619/D, *Typical Endurance for Nonvolatile Memory*.

⁴ **Typical data retention** values are based on intrinsic capability of the technology measured at high temperature and de-rated to 25 °C using the Arrhenius equation. For additional information on how Freescale defines typical data retention, please refer to Engineering Bulletin EB618/D, *Typical Data Retention for Nonvolatile Memory*.

4 Ordering Information

This chapter contains ordering information for the device numbering system.

Example of the device numbering system:



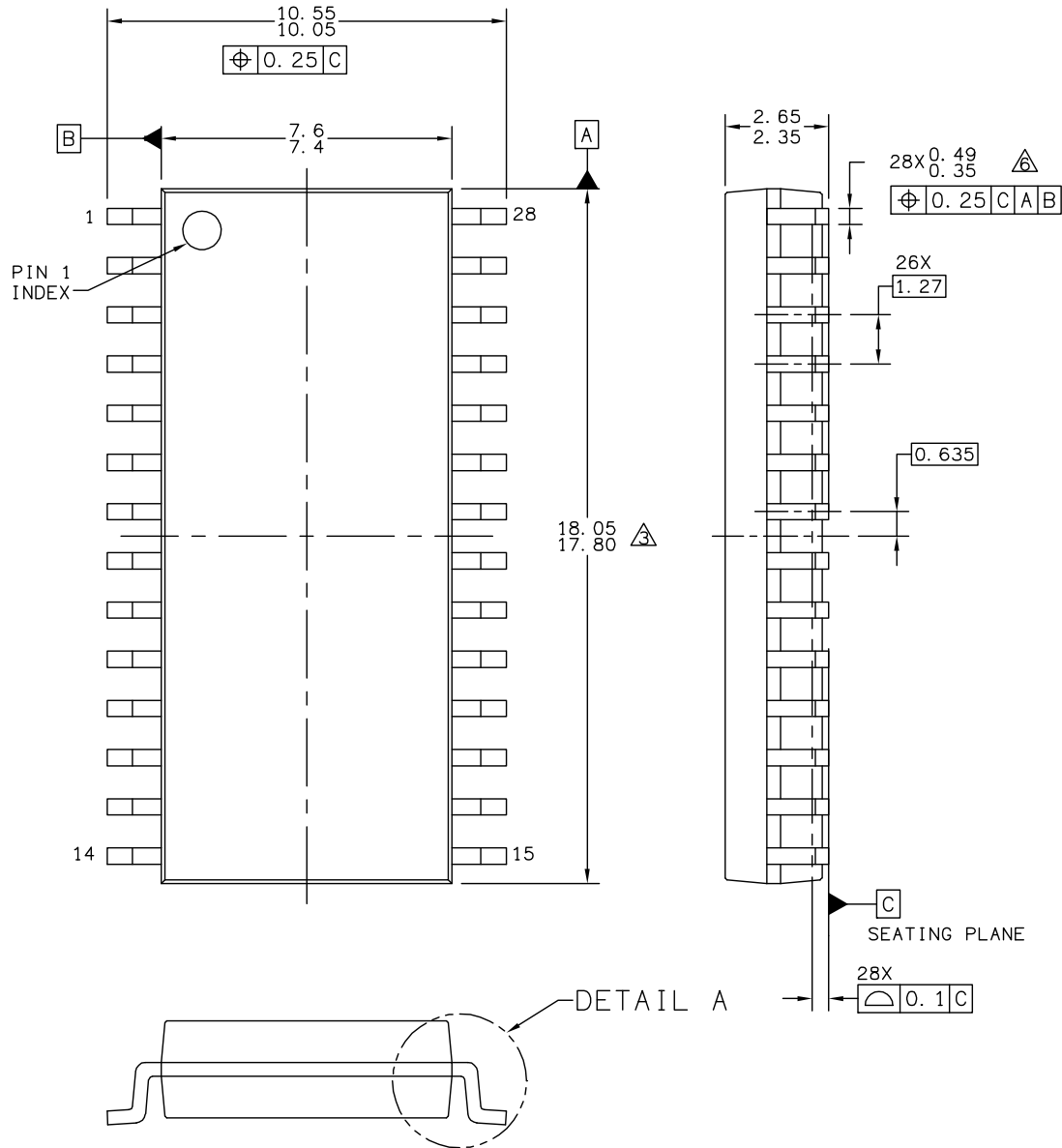
4.1 Package Information

Table 16. Package Descriptions

Pin Count	Package Type	Abbreviation	Designator	Case No.	Document No.
28	Plastic Dual In-line Pin	PDIP	RL	710	98ASB42390B
28	Small Outline Integrated Circuit	SOIC	WL	751F	98ASB42345B
16	Thin Shrink Small Outline Package	TSSOP	TG	948F	98ASH70247A

4.2 Mechanical Drawings

The following pages are mechanical drawings for the packages described in [Table 16](#).



© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICAL OUTLINE	PRINT VERSION NOT TO SCALE	
TITLE: SOIC, WIDE BODY, 28 LEAD CASEOUTLINE	DOCUMENT NO: 98ASB42345B	REV: G	
	CASE NUMBER: 751F-05	10 MAR 2005	
	STANDARD: MS-013AE		

NOTES:

1. POSITIONAL TOLERANCE OF LEADS, SHALL BE WITHIN 0.25 MM (0.010) AT MAXIMUM MATERIAL CONDITION, IN RELATION TO SEATING PLANE AND EACH OTHER.

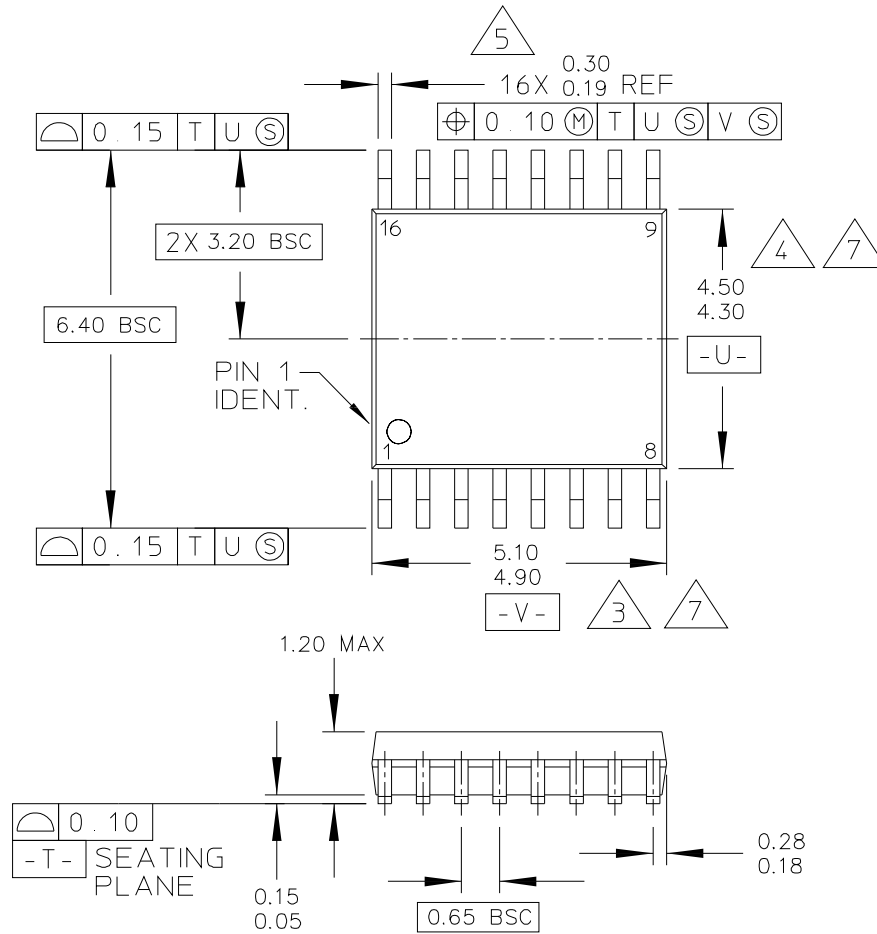
2. DIMENSION TO CENTER OF LEADS WHEN FORMED PARALLEL.

3. DIMENSION DOES NOT INCLUDE MOLD FLASH.

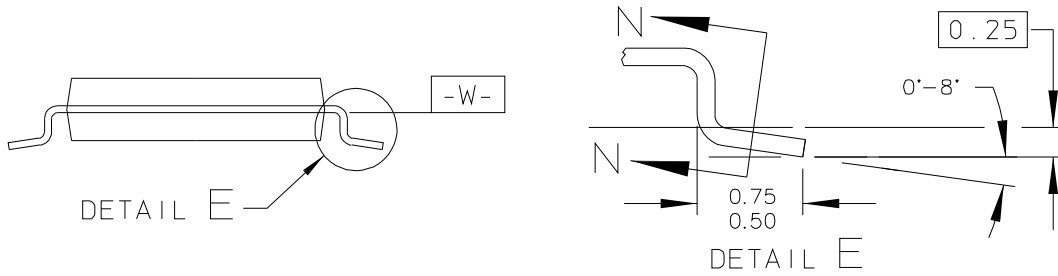
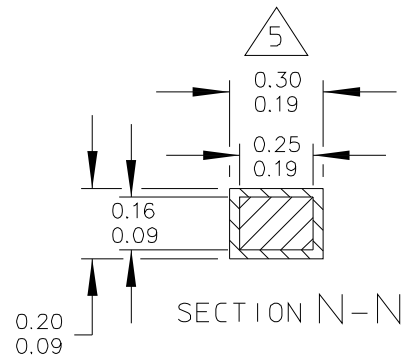
4. 710-01 OBSOLETE, NEW STD 710-02.

5. CONTROLLING DIMENSION: INCH

DIM	INCH		MILLIMETER		DIM	INCH		MILLIMETER	
	MIN	MAX	MIN	MAX		MIN	MAX	MIN	MAX
A	1.435	1.465	36.45	37.21					
B	0.540	0.560	13.72	14.22					
C	0.155	0.200	3.94	5.08					
D	0.014	0.022	0.36	0.56					
F	0.040	0.060	1.02	1.52					
G	0.100 BSC		2.54 BSC						
H	0.065	0.085	1.65	2.16					
J	0.008	0.015	0.20	0.38					
K	0.115	0.135	2.92	3.43					
L	0.600 BSC		15.24 BSC						
M	0°	15°	0°	15°					
N	0.020	0.040	0.51	1.02					
© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.			MECHANICAL OUTLINE		PRINT VERSION NOT TO SCALE				
TITLE: 28 LD PDIP					DOCUMENT NO: 98ASB42390B			REV: D	
					CASE NUMBER: 710-02			24 MAY 2005	
					STANDARD: NON-JEDEC				



© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICAL OUTLINE	PRINT VERSION NOT TO SCALE	
TITLE: 16 LD TSSOP, PITCH 0.65MM	DOCUMENT NO: 98ASH70247A	REV: B	
	CASE NUMBER: 948F-01	19 MAY 2005	
	STANDARD: JEDEC		



© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICAL OUTLINE	PRINT VERSION NOT TO SCALE	
TITLE: 16 LD TSSOP, PITCH 0.65MM	DOCUMENT NO: 98ASH70247A	REV: B	
	CASE NUMBER: 948F-01	19 MAY 2005	
	STANDARD: JEDEC		

How to Reach Us:

Home Page:

www.freescale.com

Web Support:

<http://www.freescale.com/support>

USA/Europe or Locations Not Listed:

Freescale Semiconductor, Inc.
Technical Information Center, EL516
2100 East Elliot Road
Tempe, Arizona 85284
1-800-521-6274 or +1-480-768-2130
www.freescale.com/support

Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH
Technical Information Center
Schatzbogen 7
81829 Muenchen, Germany
+44 1296 380 456 (English)
+46 8 52200080 (English)
+49 89 92103 559 (German)
+33 1 69 35 48 48 (French)
www.freescale.com/support

Japan:

Freescale Semiconductor Japan Ltd.
Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku,
Tokyo 153-0064
Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:

Freescale Semiconductor China Ltd.
Exchange Building 23F
No. 118 Jianguo Road
Chaoyang District
Beijing 100022
China
+86 10 5879 8000
support.asia@freescale.com

Information in this document is provided solely to enable system and software implementers to use Freescale Semiconductor products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters that may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals", must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

RoHS-compliant and/or Pb-free versions of Freescale products have the functionality and electrical characteristics as their non-RoHS-compliant and/or non-Pb-free counterparts. For further information, see <http://www.freescale.com> or contact your Freescale sales representative.

For information on Freescale's Environmental Products program, go to <http://www.freescale.com/epp>.

Freescale and the Freescale logo are trademarks of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners.

© Freescale Semiconductor, Inc. 2008-2009, 2015. All rights reserved.

Document Number: MC9S08SE8

Rev. 4

4/2015